Claims

[Claim 1]

A polycrystalline silicon rod comprising:

a core wire formed of silicon, wherein

an iron concentration is 20 pptw or less in terms of elements, a nickel concentration is 5 pptw or less in terms of elements and a total metal concentration of iron and nickel is 25 pptw or less in terms of elements in a region within 2 mm from an interface between the core wire and polycrystalline silicon deposited on a surface of the core wire.

[Claim 2]

The polycrystalline silicon rod according to claim 1, wherein

in the region, a chromium concentration is 5 pptw or less in terms of elements.